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April 2015

FGH40N65UFD\_F085 650 V, 40 A Field Stop IGBT

## FGH40N65UFD\_F085 650 V, 40 A Field Stop IGBT

### **Features**

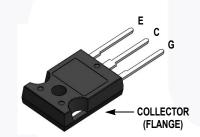
- · High Current Capability
- Low Saturation Voltage:  $V_{CE(sat)}$  = 1.8 V @ I<sub>C</sub> = 40 A
- · High Input Impedance
- · Fast Switching
- RoHS Compliant
- · Qualified to Automotive Requirements of AEC-Q101

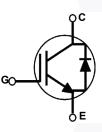
### Applications

- · Automotive Chargers, Converters, High Voltage Auxiliaries
- Inverters, PFC, UPS

### **General Description**

Using novel field stop IGBT technology, Fairchild's field stop IGBTs offer the optimum performance for Automotive Chargers, Inverter, and other applications where low conduction and switching losses are essential.





### **Absolute Maximum Ratings**

Symbol	Description		Ratings	Unit
V <sub>CES</sub>	Collector to Emitter Voltage		650	V
V <sub>GES</sub>	Gate to Emitter Voltage		± 20	V
I <sub>C</sub>	Collector Current	@ T <sub>C</sub> = 25°C	80	A
	Collector Current	@ T <sub>C</sub> = 100°C	40	A
I <sub>CM (1)</sub>	Pulsed Collector Current	@ T <sub>C</sub> = 25 <sup>o</sup> C	120	А
P <sub>D</sub>	Maximum Power Dissipation	@ T <sub>C</sub> = 25°C	290	W
	Maximum Power Dissipation	@ T <sub>C</sub> = 100°C	116	W
TJ	Operating Junction Temperature		-55 to +150	°C
T <sub>stg</sub>	Storage Temperature Range		-55 to +150	°C
TL	Maximum Lead Temp. for soldering Purposes, 1/8" from case for 5 seconds		300	°C

Notes: 1: Repetitive rating: Pulse width limited by max. junction temperature

### **Thermal Characteristics**

Symbol	Parameter	Тур	Unit	
$R_{\theta JC}(IGBT)$	Thermal Resistance, Junction to Case	0.43	°C/W	
$R_{\theta JC}(Diode)$	Thermal Resistance, Junction to Case	1.45	°C/W	
$R_{\thetaJA}$	Thermal Resistance, Junction to Ambient	40	°C/W	

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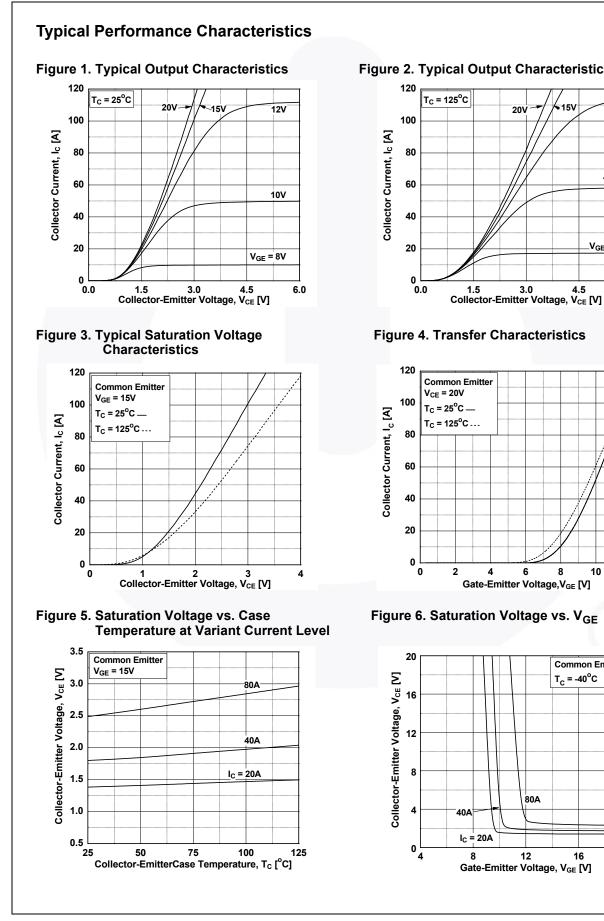
### Package Marking and Ordering Information

Part Number	Top Mark	Package	Packing Method	Reel Size	Tape Width	Quantity
FGH40N65UFDTU_F085	FGH40N65UFD	TO-247	Tube	N/A	N/A	30

### Electrical Characteristics of the IGBT T<sub>C</sub> = 25°C unless otherwise noted

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
Off Charac	teristics					
BV <sub>CES</sub>	Collector to Emitter Breakdown Voltage	V <sub>GE</sub> = 0 V, I <sub>C</sub> = 250 μA	650	-	-	V
ΔΒV <sub>CES</sub> ΔΤ <sub>J</sub>	Temperature Coefficient of Breakdown Voltage	$V_{GE}$ = 0 V, I <sub>C</sub> = 250 $\mu$ A	-	0.6	-	V/ºC
I <sub>CES</sub>	Collector Cut-Off Current	$V_{CE} = V_{CES}, V_{GE} = 0 V$	-	-	250	μA
I <sub>GES</sub>	G-E Leakage Current	$V_{GE}$ = $V_{GES}$ , $V_{CE}$ = 0 V	-	-	±400	nA
On Charac	teristics					
V <sub>GE(th)</sub>	G-E Threshold Voltage	I <sub>C</sub> = 250 μA, V <sub>CE</sub> = V <sub>GE</sub>	4.0	5.2	6.5	V
		$I_{\rm C}$ = 40 A, $V_{\rm GE}$ = 15 V	-	1.8	2.4	V
V <sub>CE(sat)</sub>	Collector to Emitter Saturation Voltage	$I_{C} = 40 \text{ A}, V_{GE} = 15 \text{ V},$ $T_{C} = 125^{\circ}\text{C}$	-	2.0	-	V
Dynamic C	Characteristics				1	
C <sub>ies</sub>	Input Capacitance		-	1860	-	pF
C <sub>oes</sub>	Output Capacitance	$V_{CE} = 30 V, V_{GE} = 0 V,$	-	200	-	pF
C <sub>res</sub>	Reverse Transfer Capacitance	f = 1 MHz	-	65	-	pF
	Characteristics		-	23	-	ns
t <sub>d(on)</sub> t <sub>r</sub>	Rise Time	-	-	35	-	ns
t <sub>d(off)</sub>	Turn-Off Delay Time	1 = 100  V = 100  A	-	126	-	ns
t <sub>f</sub>	Fall Time	$V_{CC} = 400 \text{ V}, \text{ I}_{C} = 40 \text{ A},$ $R_{G} = 10 \Omega, V_{GE} = 15 \text{ V},$ Inductive Load, $T_{C} = 25^{\circ}\text{C}$	-	26	60	ns
E <sub>on</sub>	Turn-On Switching Loss		-	1.28	- /	mJ
E <sub>off</sub>	Turn-Off Switching Loss	-	-	0.50	-	mJ
E <sub>ts</sub>	Total Switching Loss			1.78		mJ
t <sub>d(on)</sub>	Turn-On Delay Time		-	21	-	ns
t <sub>r</sub>	Rise Time	-	-	39	-	ns
t <sub>d(off)</sub>	Turn-Off Delay Time	V <sub>CC</sub> = 400 V, I <sub>C</sub> = 40 A,	-	131	-	ns
t <sub>f</sub>	Fall Time	R <sub>G</sub> = 10 Ω, V <sub>GE</sub> = 15 V,	-	72	-	ns
Eon	Turn-On Switching Loss	Inductive Load, $T_C = 125^{\circ}C$	-	1.62	-	mJ
E <sub>off</sub>	Turn-Off Switching Loss		-	0.79	-	mJ
	Total Switching Loss		-	2.41	-	mJ
Ets			-	119	-	nC
	Total Gate Charge		_	110		
E <sub>ts</sub> Q <sub>g</sub> Q <sub>ge</sub>	Total Gate Charge Gate to Emitter Charge	V <sub>CE</sub> = 400 V, I <sub>C</sub> = 40 A, V <sub>GE</sub> = 15 V	-	14	-	nC

Symbol	Parameter	Test Condition	ns	Min.	Тур.	Max	Unit
V <sub>FM</sub> Diode Forward Voltage	I <sub>F</sub> = 20 A	T <sub>C</sub> = 25°C	-	1.80	2.6	v	
	blode i olivara voltage	1F 207	T <sub>C</sub> = 125 <sup>o</sup> C	-	1.71	-	
t	Diode Reverse Recovery Time	I <sub>F</sub> =20 A, di <sub>F</sub> /dt = 200 A/μs	T <sub>C</sub> = 25 <sup>o</sup> C	-	65	-	ns
۲r			T <sub>C</sub> = 125°C	-	215	-	
Q <sub>rr</sub>	Diode Reverse Recovery Charge	$r_{\rm F} = 20$ Å, $a_{\rm F} a_{\rm C} = 200$ Å/µ3	T <sub>C</sub> = 25 <sup>o</sup> C	-	145	-	nC
α <sub>f</sub> r			T <sub>C</sub> = 125 <sup>o</sup> C	-	775	-	



**Figure 2. Typical Output Characteristics** 

20

6

80A

12

8

10

**Common Emitter** 

 $T_c = -40^{\circ}C$ 

16

12

15V

12V

10V

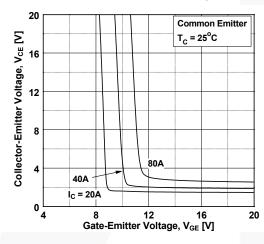
V<sub>GE</sub> = 8V

6.0

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### **Typical Performance Characteristics**

#### Figure 7. Saturation Voltage vs. V<sub>GE</sub>



**Figure 9. Capacitance Characteristics** 

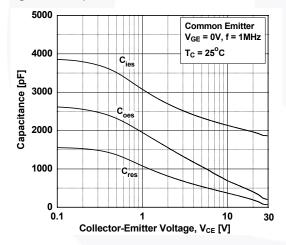


Figure 11. SOA Characteristics

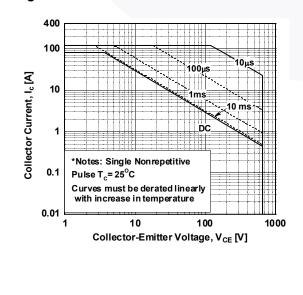
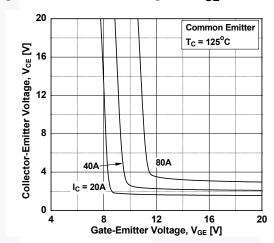
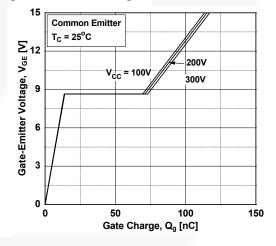


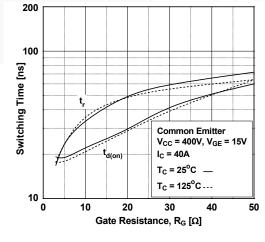
Figure 8. Saturation Voltage vs. VGE











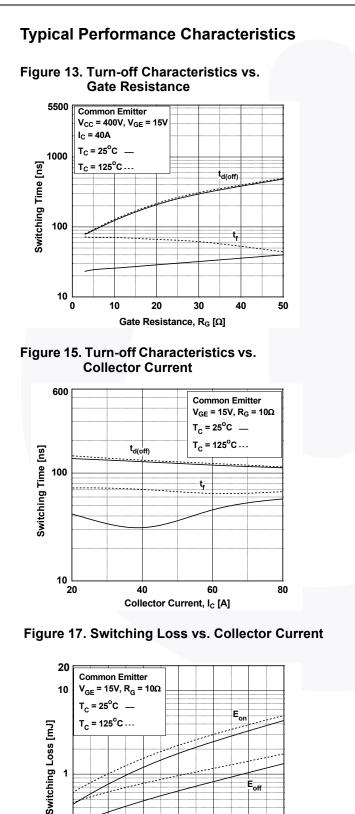
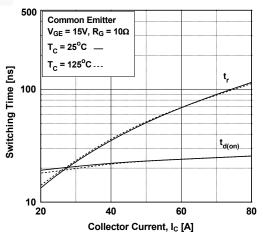
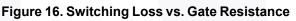
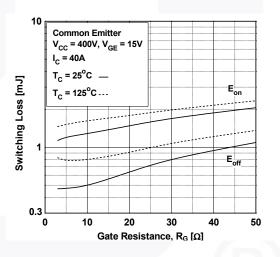
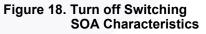


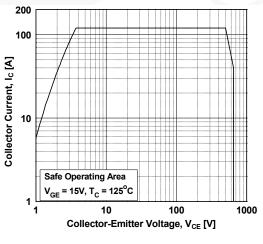
Figure 14. Turn-on Characteristics vs. **Collector Current** 











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Collector Current, Ic [A]

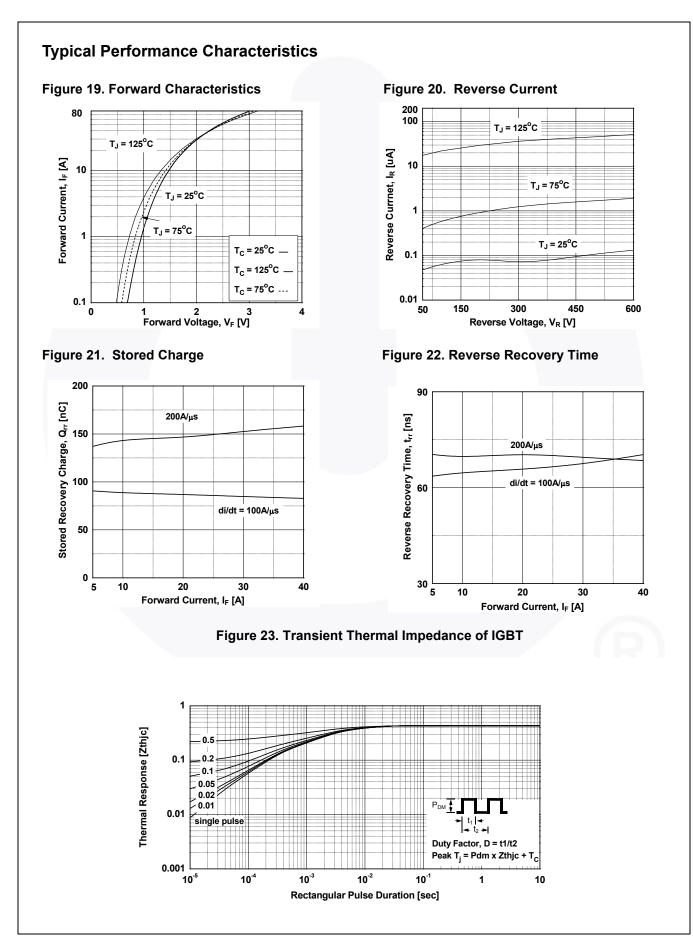
60

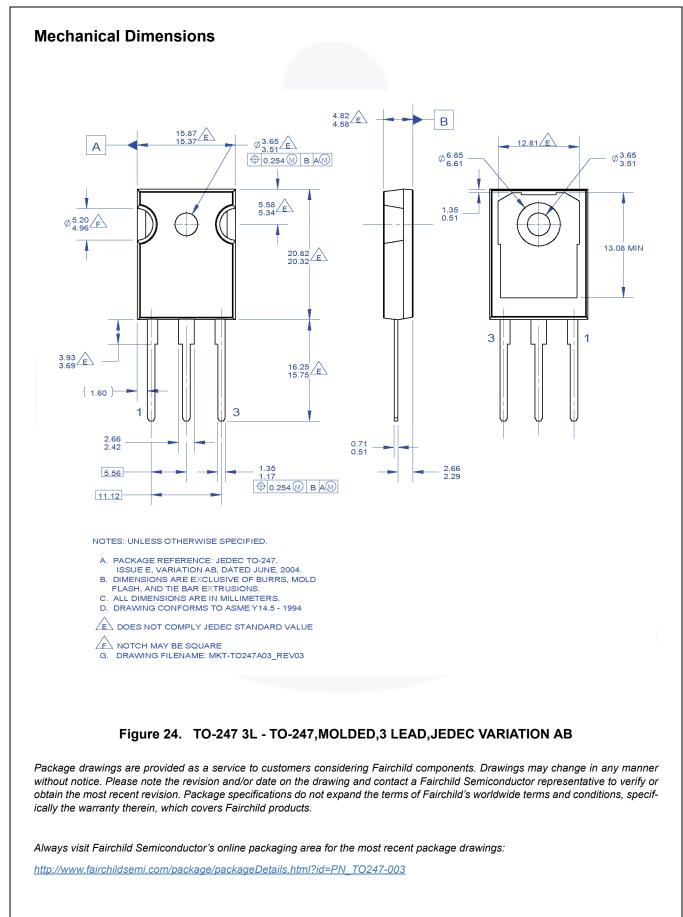
E<sub>off</sub>

70

80









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